



FAKULTAD DE CIENCIAS FÍSICAS
INSTITUTO DE INVESTIGACIÓN
UNIDAD DE POSGRADO



XXXI Simposio Peruano de Física

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15-19 diciembre 2025

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America/Lima timezone



Propiedades electrónicas y magnéticas de canales de grafeno grabados en fluorografeno: Transición controlable de semiconductor a metal.

Expositor: Dr. R. M. Guzmán-Arellano

 Dr Alexander David Hernadez Nieves (Centro Atomico Baril...)

 Dr Francois Peeters (Nanjing University of...)

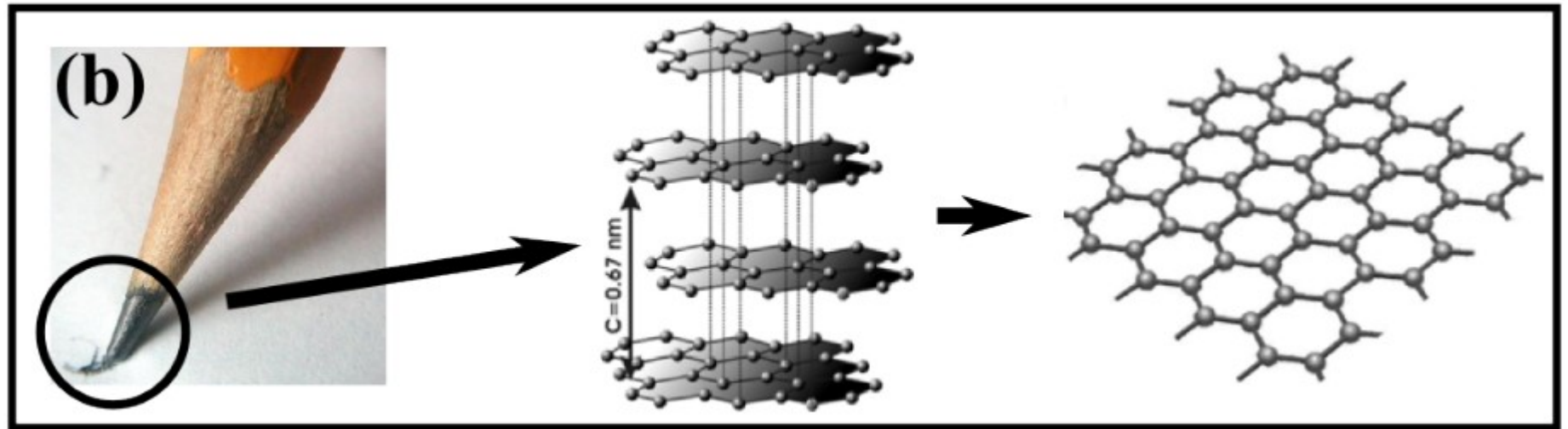
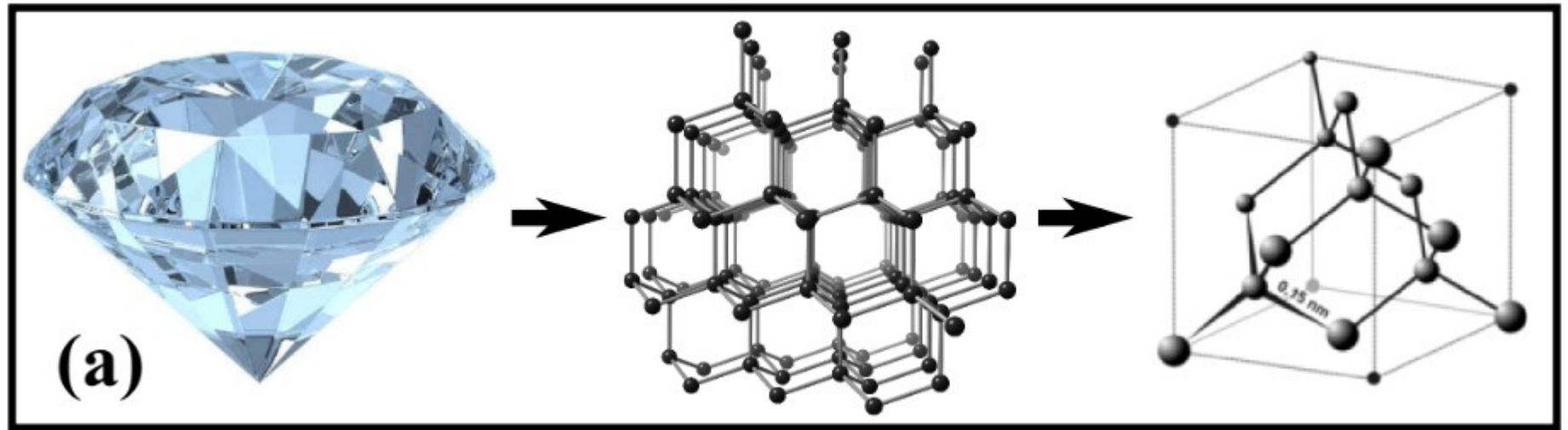
 Dr Gonzalo Usaj (Cemtrp Atomico Bari...)



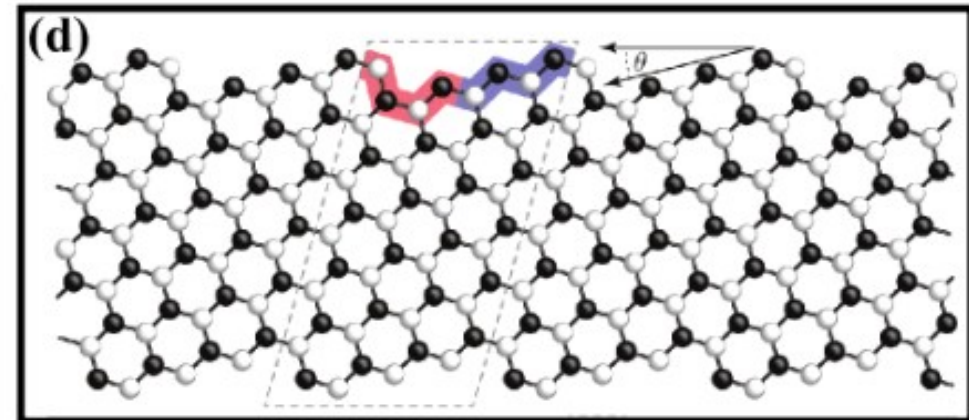
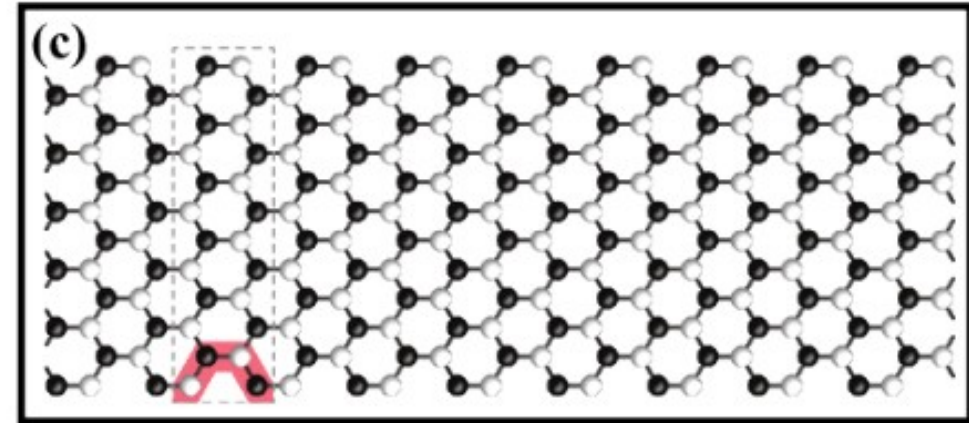
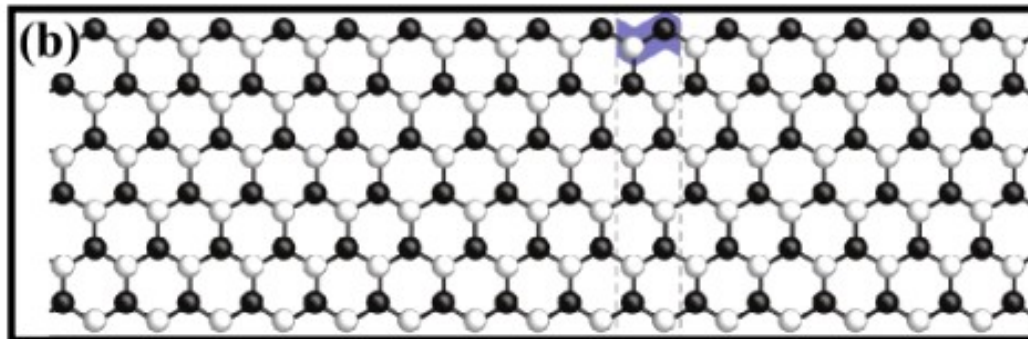
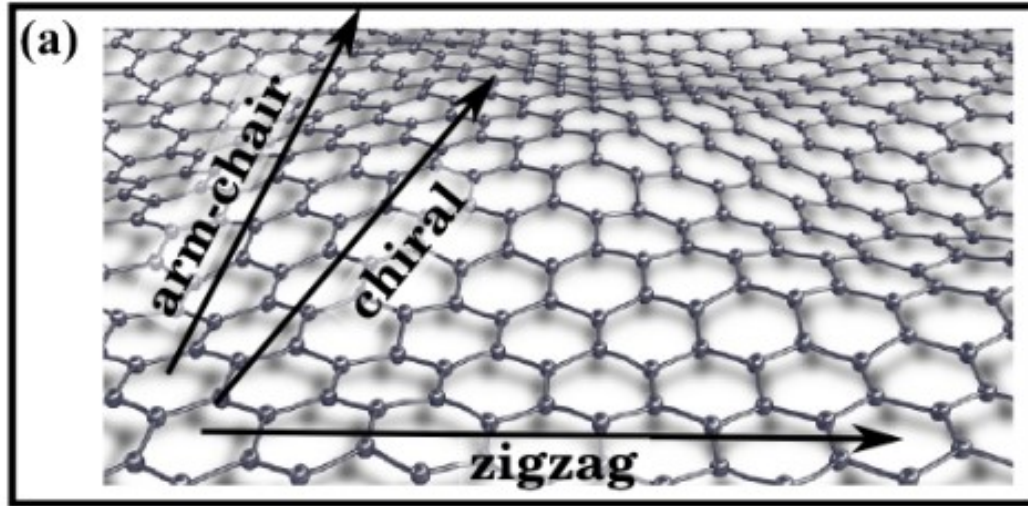
Organización

- 1) Compuestos de Carbono.**
- 2) Grafeno – Nano cintas de grafeno.**
- 3) Fluorografeno.**
- 4) Canales de Grafeno – Resultados de primeros principios.**
- 5) Ajuste de Wannier – Verificación de parámetros.**
- 6) Modelo de Hubbard y método Hartree-Fock.**
- 7) Ajuste de los resultados DFT.**
- 8) Conclusiones – Referencias.**

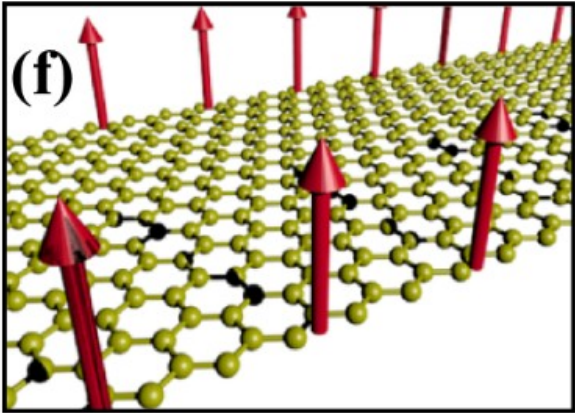
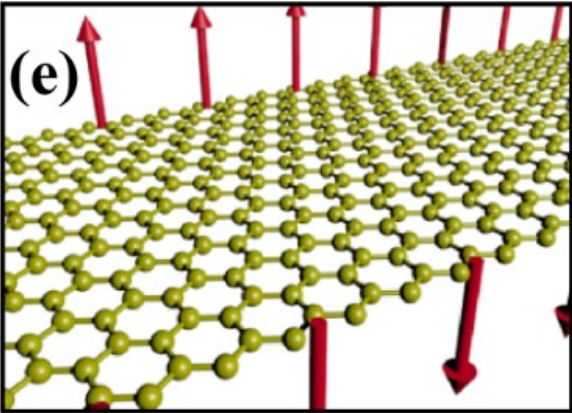
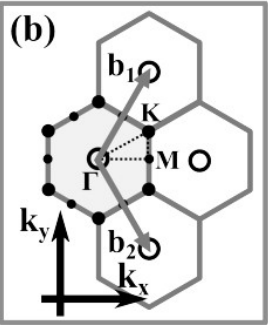
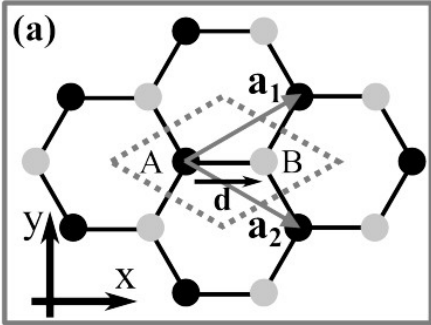
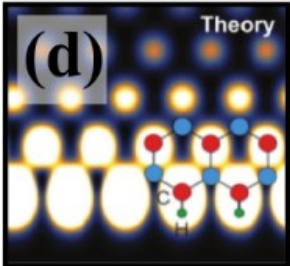
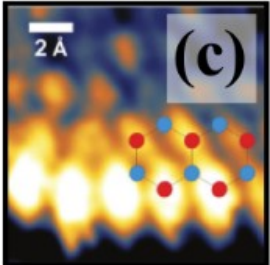
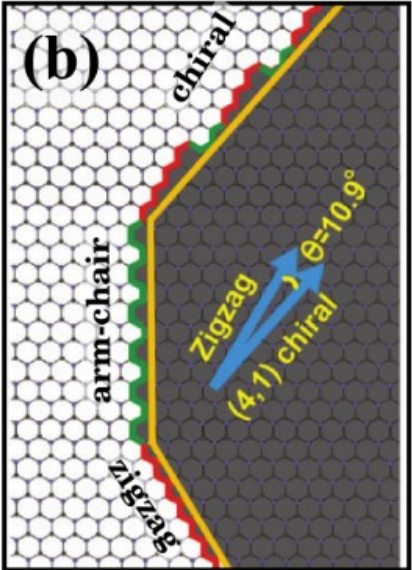
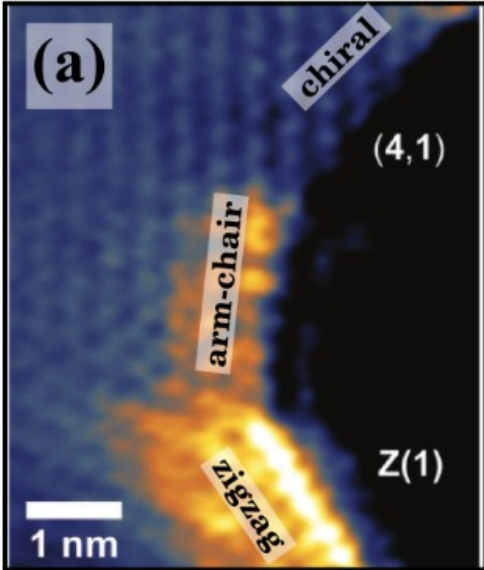
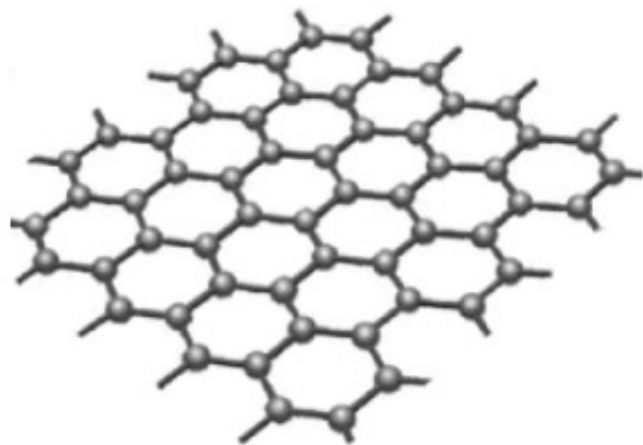
Compuestos de Carbono.



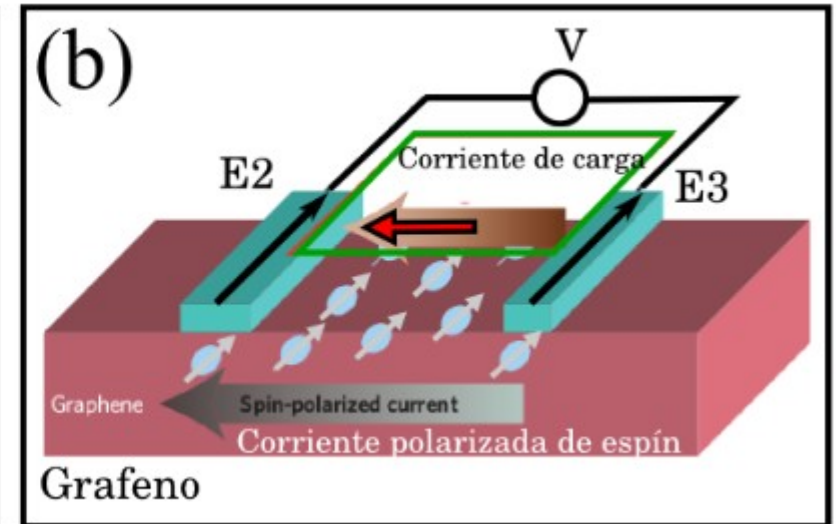
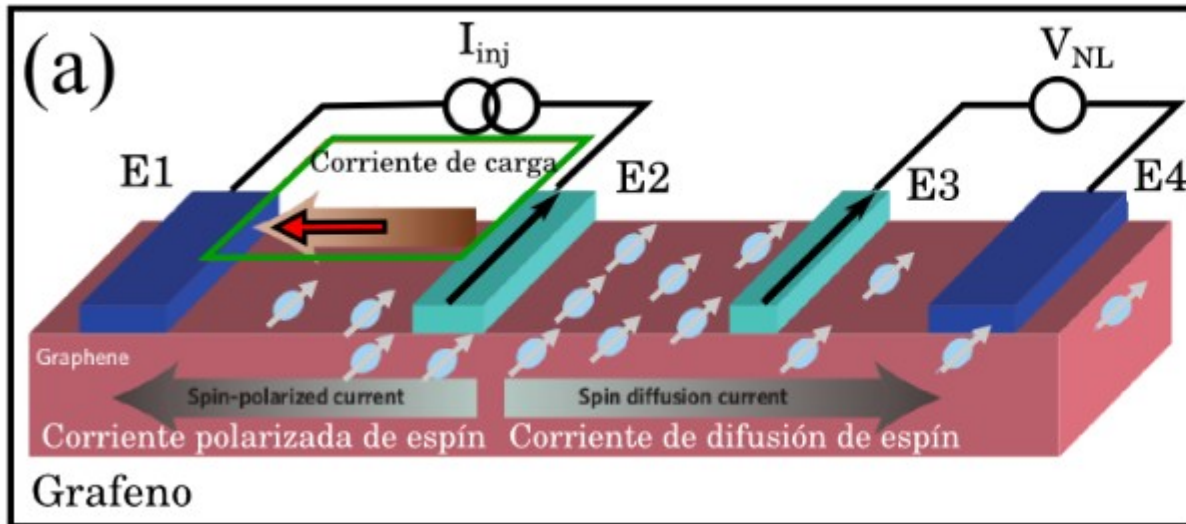
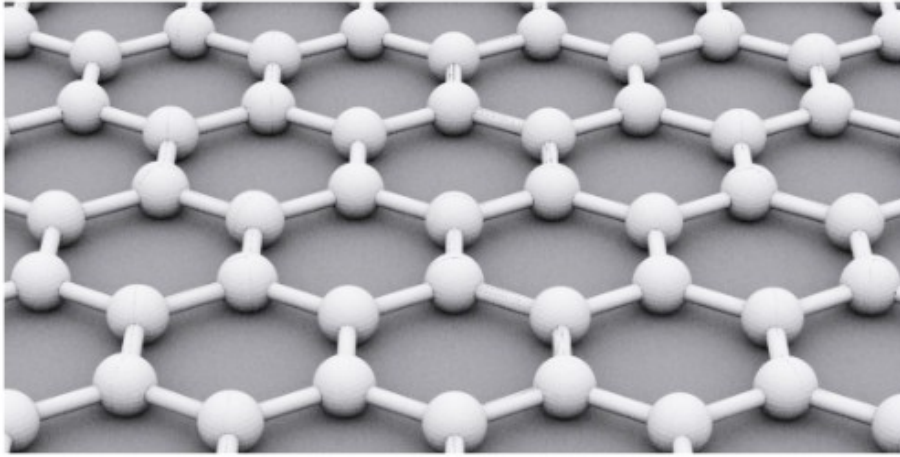
Grafeno – Nano cintas de grafeno



Grafeno – Nano cintas de grafeno



Grafeno – Nano cintas de grafeno



Grafeno – Nano cintas de grafeno

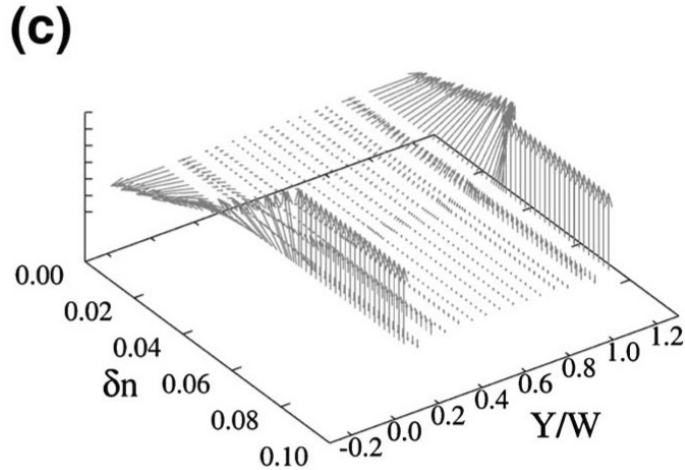
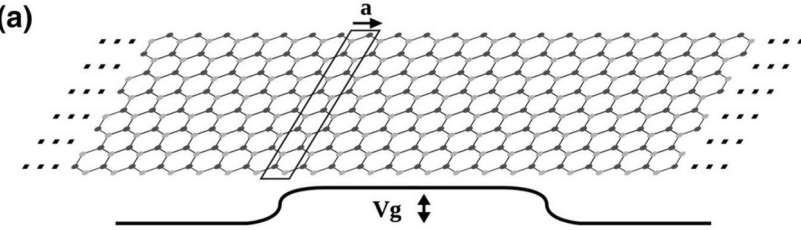
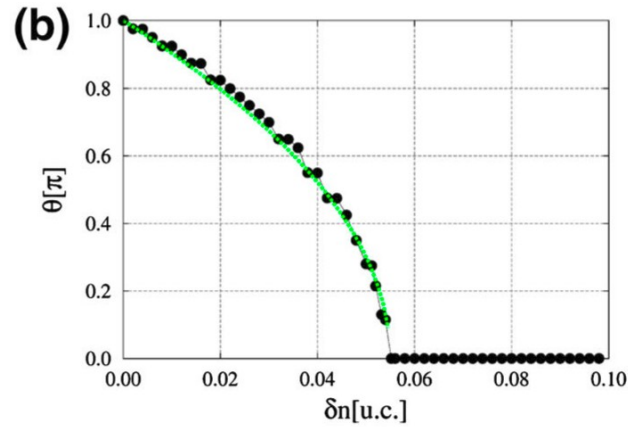
Transmission Through Gate-Induced Magnetic Islands on Graphene Nanoribbons

R. M. Guzmán Arellano · Gonz:(a)

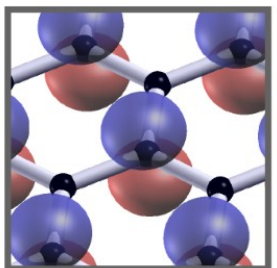
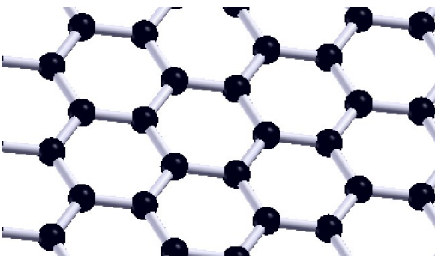
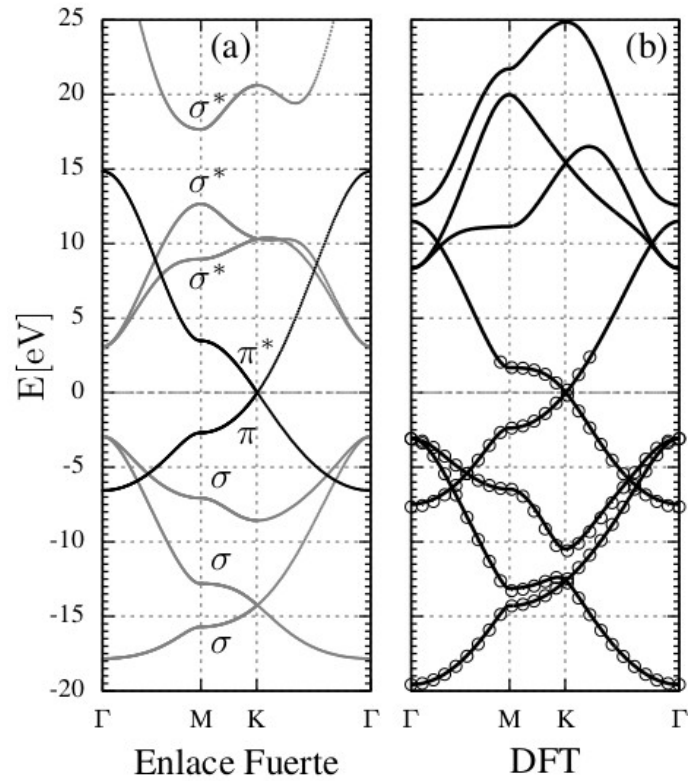
Received: 4 August 2014 / Accepted: 10 September 2014
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Abstract We study the spin-dependent transmission through a potential barrier in a zigzag graphene nanoribbon. In particular, we consider the effect of the magnetic order of the ribbon induced by the modulation of the local density introduced by the barrier. We model the system using an Anderson–Hubbard model that we treat in the mean field approximation. We solve this problem self-consistently and calculate the transmission coefficient using the recursive Green function method. We find that Fano-like interference dips appear on one of the spin channels as the result of the presence of spin polarized edge states in the barrier.

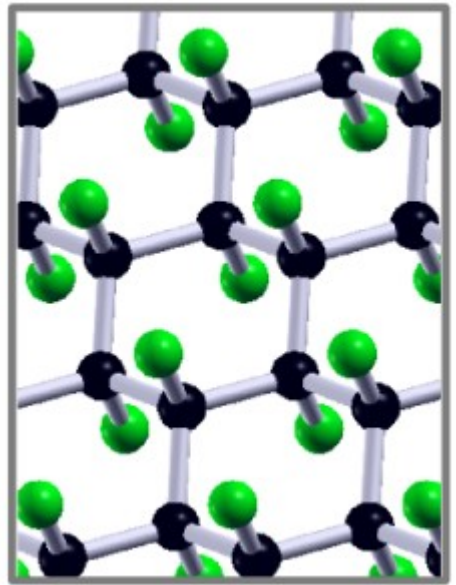
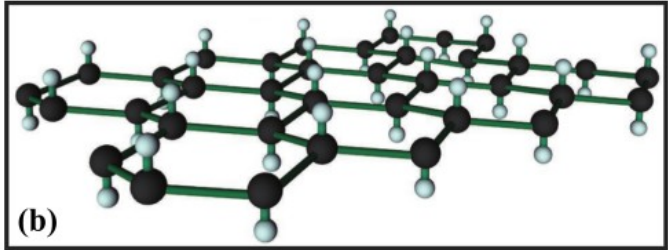
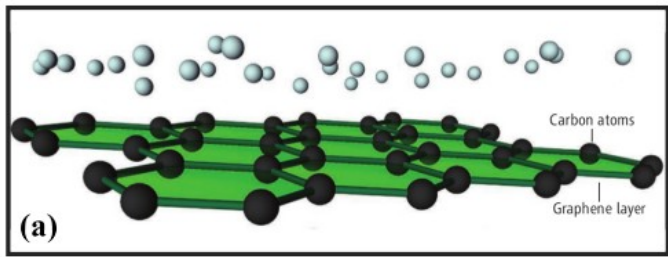
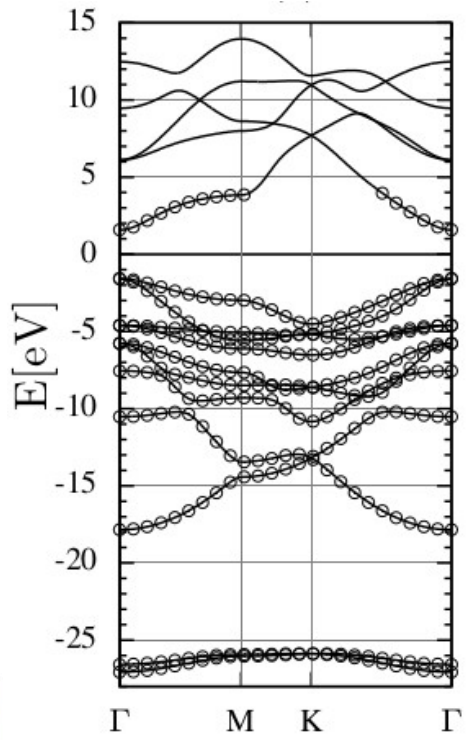
Keywords Graphene · Spin-dependent transport · Nanoribbons



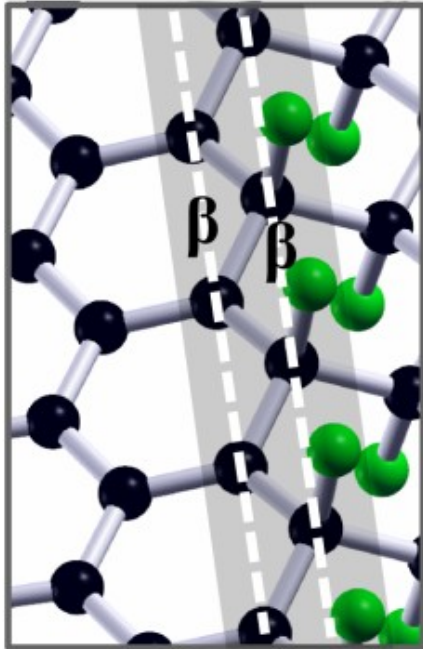
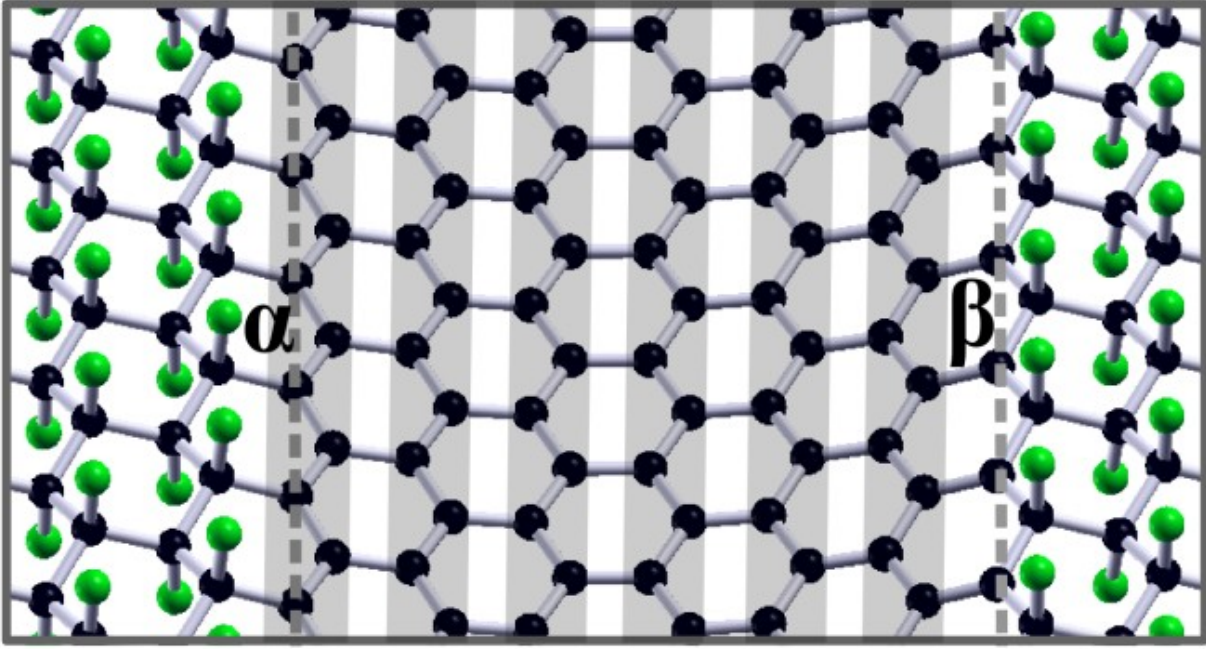
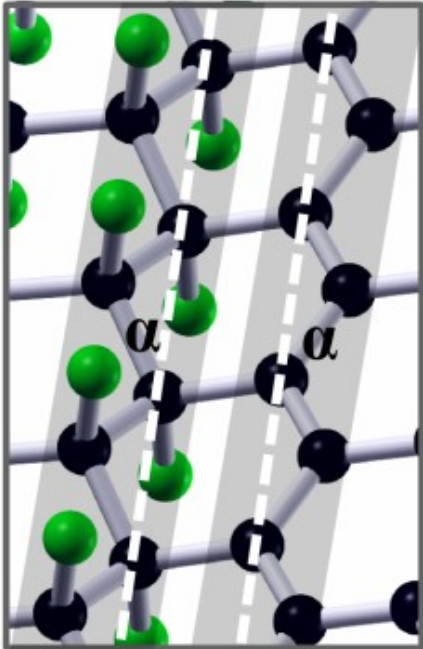
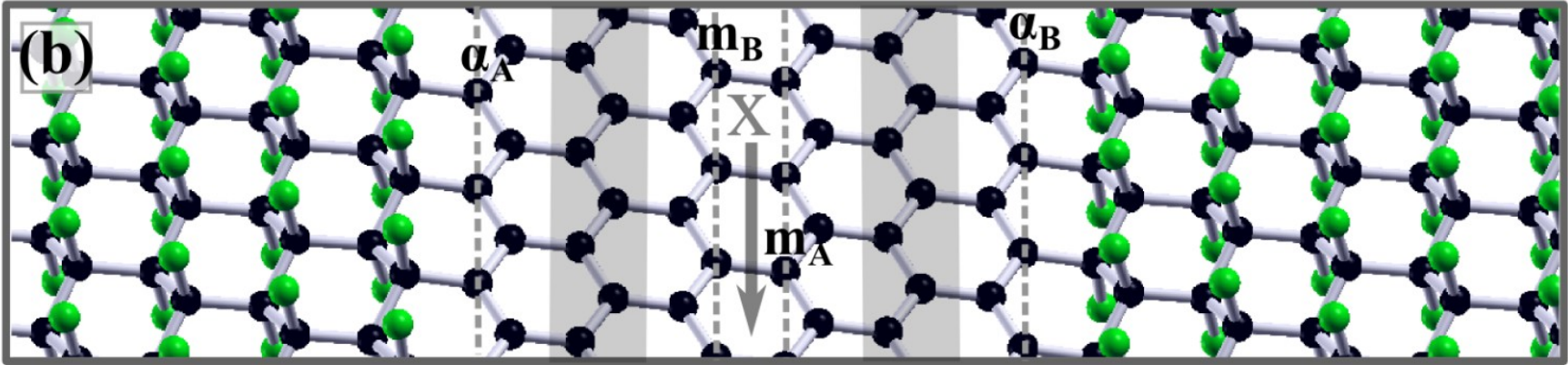
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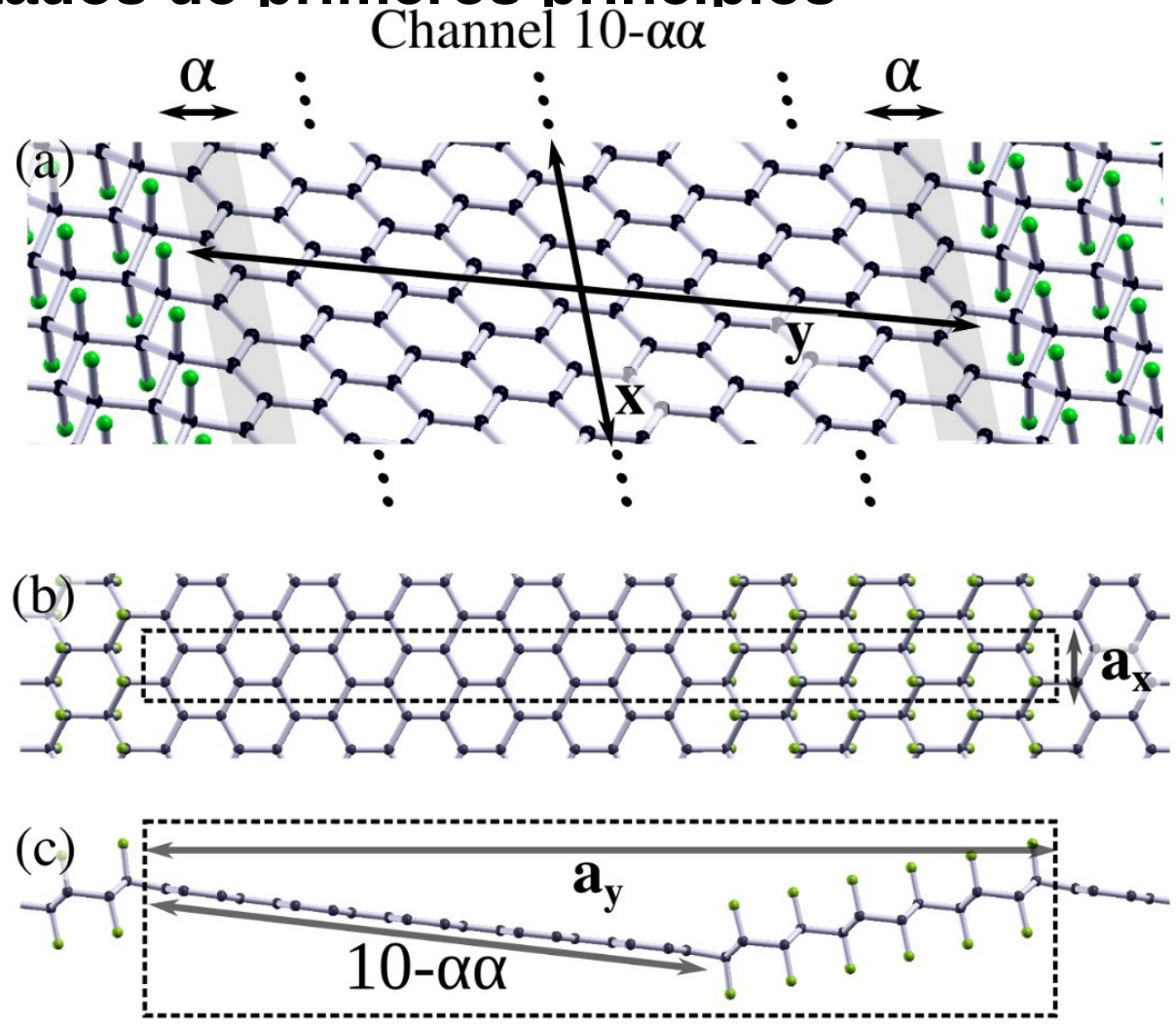
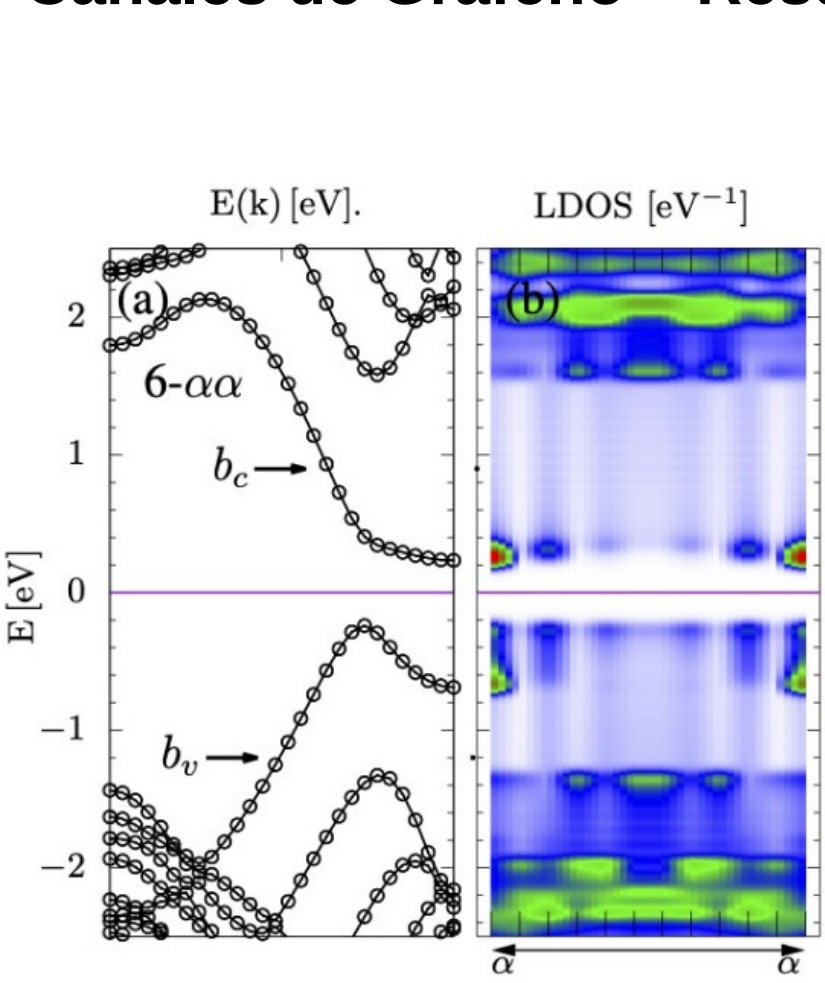
Fluorografeno



Canales de Grafeno – Resultados de primeros principios

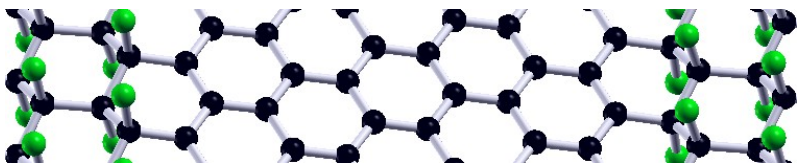


Canales de Grafeno – Resultados de primeros principios

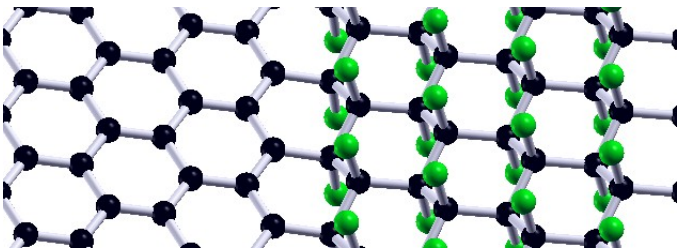
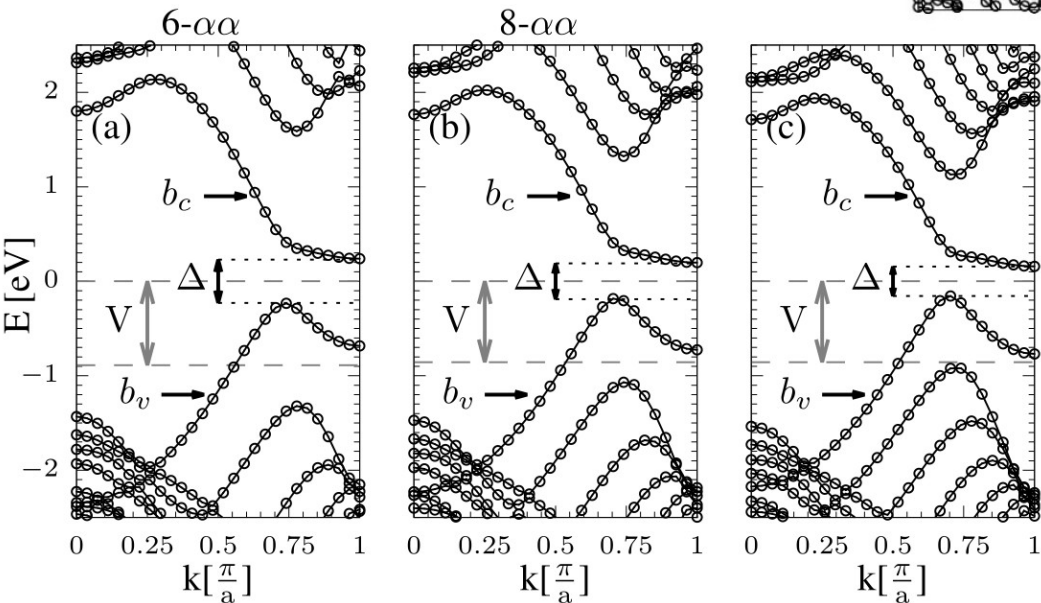
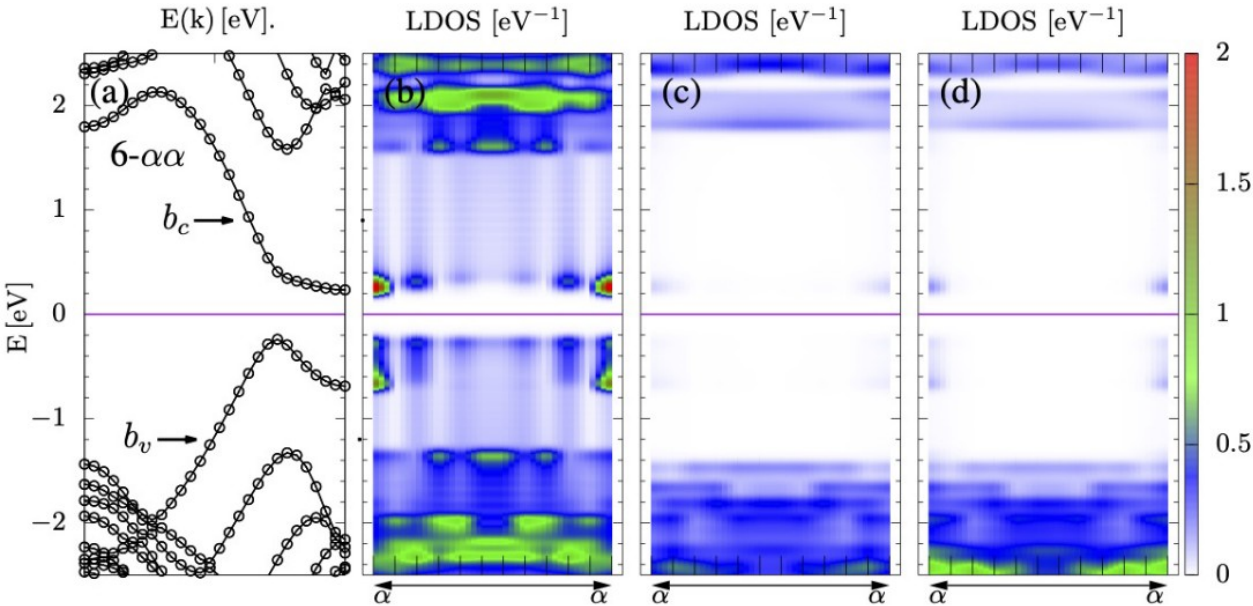


Canales de Grafeno

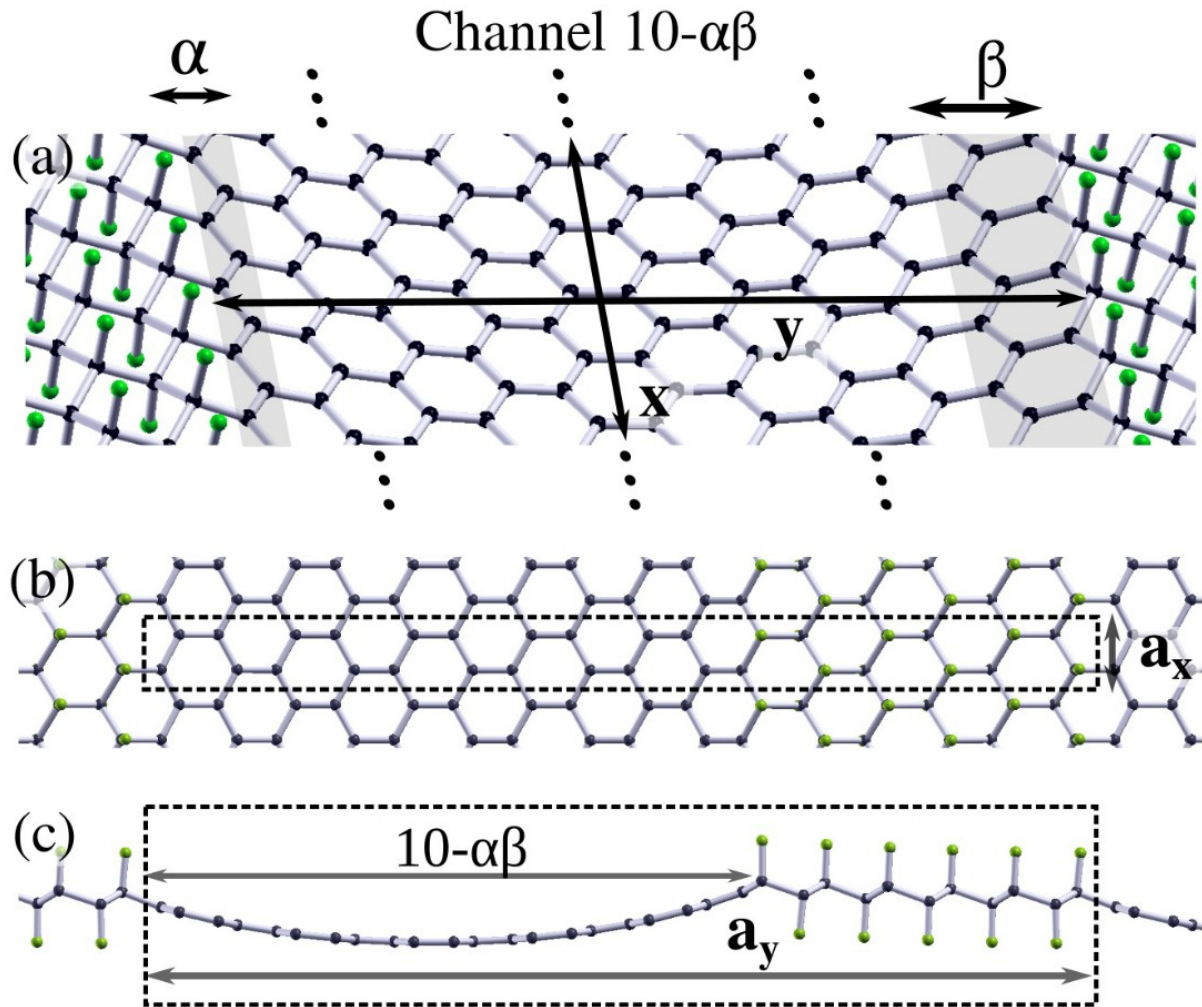
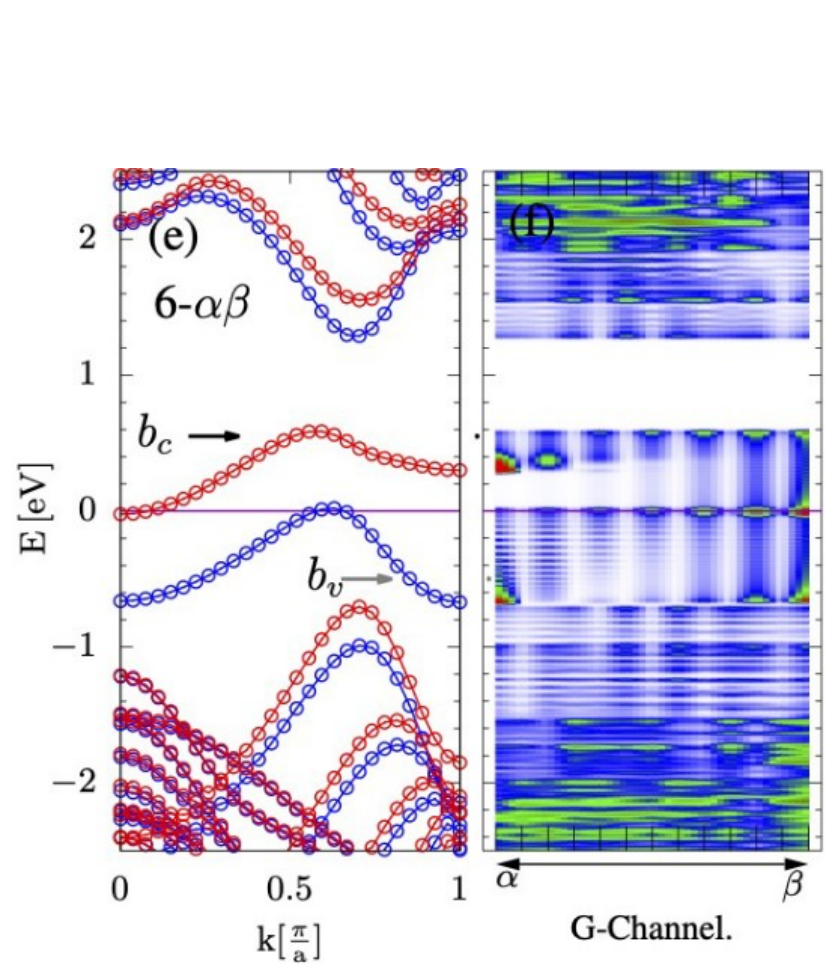
Resultados de primeros principios



Sistema	θ	a_y	M_{abs}	M_α	Δ
6- $\alpha\alpha$	20.5°	25.85Å	1.10 μ_B	0.30 μ_B	0.47eV
8- $\alpha\alpha$	19.7°	30.09Å	1.16 μ_B	0.30 μ_B	0.38eV
10- $\alpha\alpha$	18.7°	34.33Å	1.23 μ_B	0.30 μ_B	0.31eV

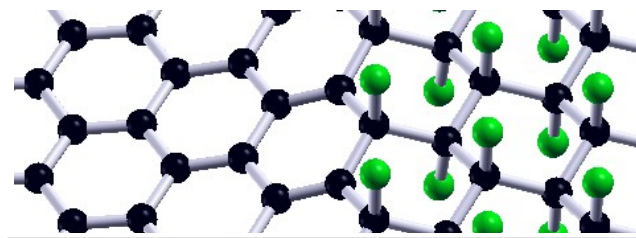
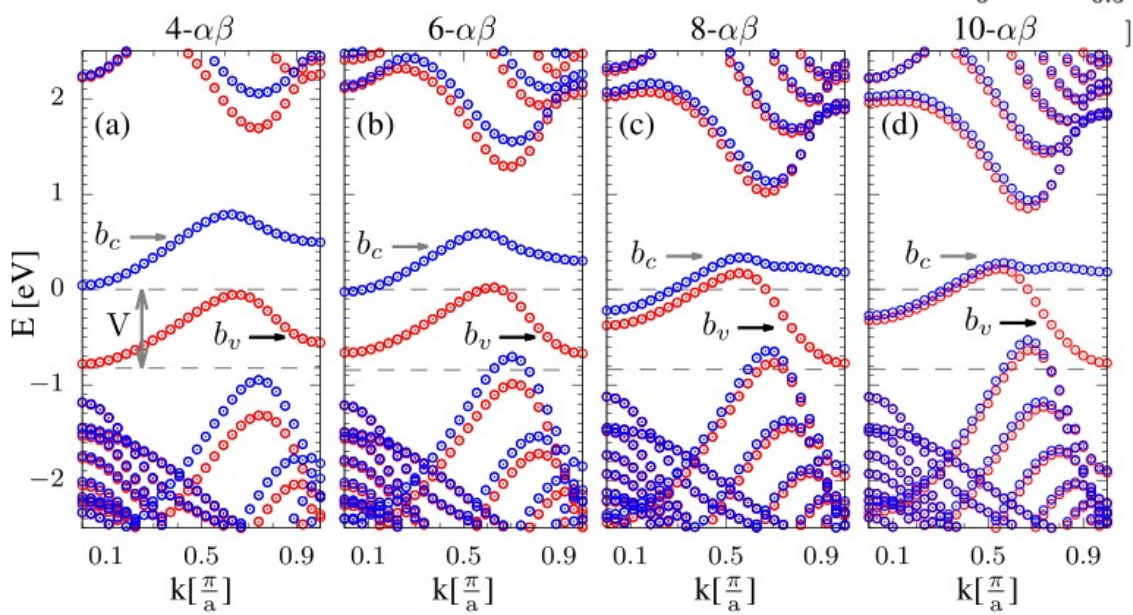
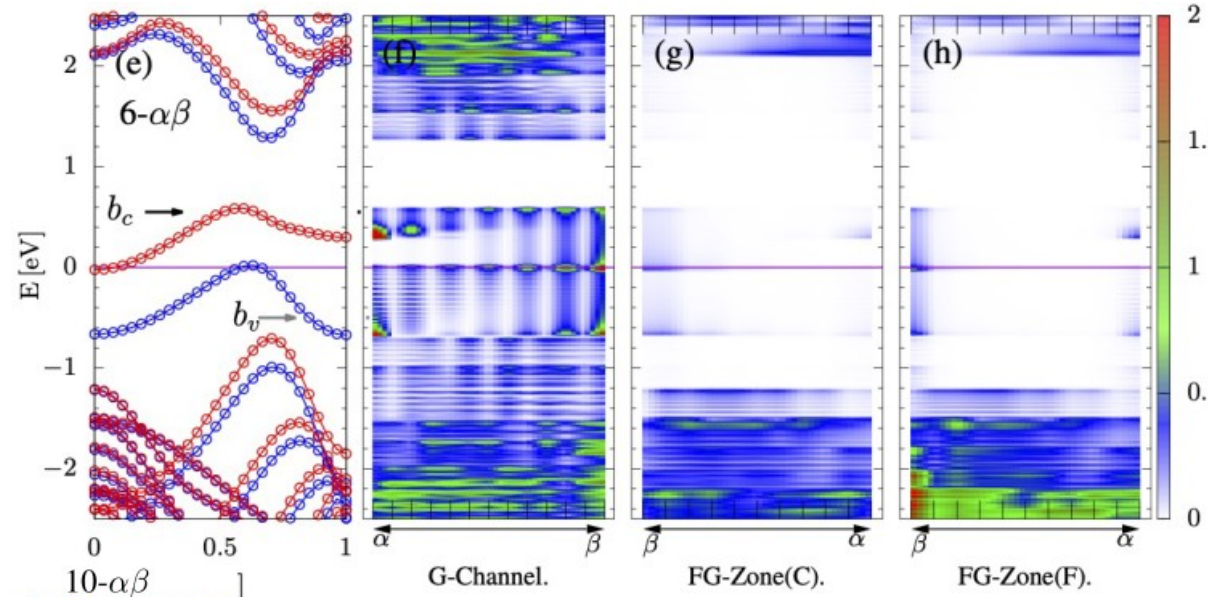
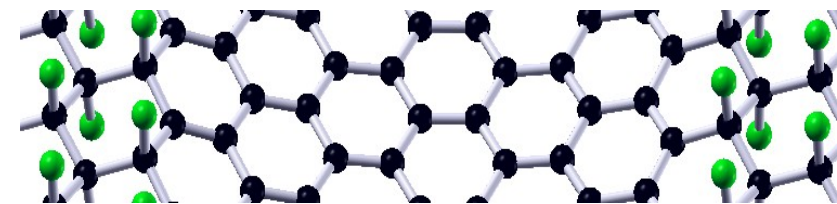


Canales de Grafeno – Resultados de primeros principios



Canales de Grafeno

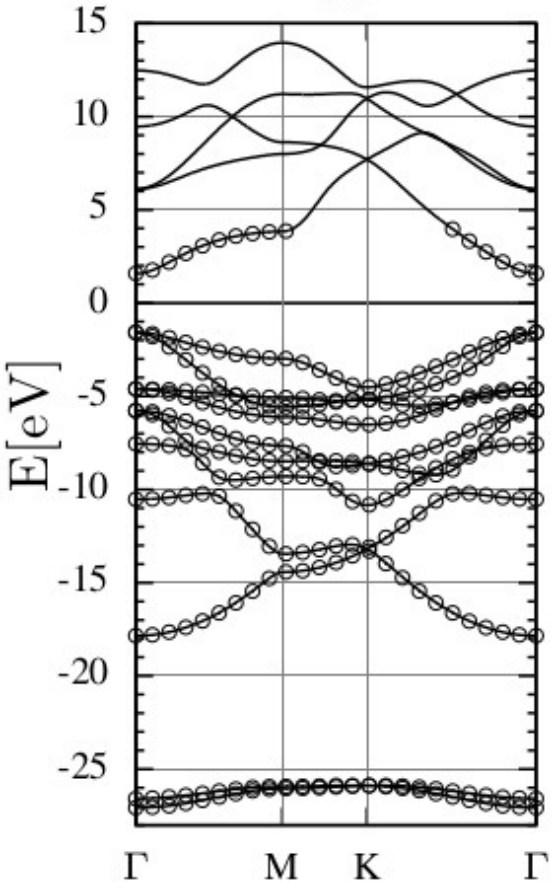
Resultados de primeros principios



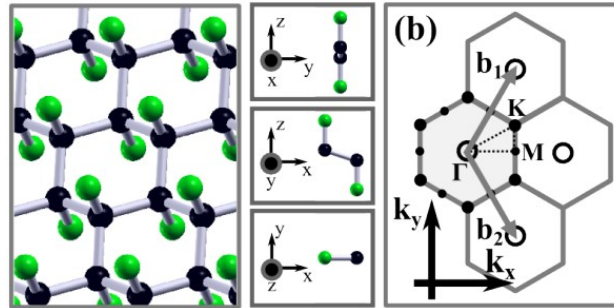
Channel	a_y (Å)	$M_{\text{abs}} (\mu_B)$	$M_t (\mu_B)$	$M_\beta (\mu_B)$	$M_\alpha (\mu_B)$
$4-\alpha\beta$	21.75	1.60	0.97	0.38	0.34
$6-\alpha\beta$	25.83	1.47	0.84	0.31	0.31
$8-\alpha\beta$	30.06	0.82	0.45	0.08	0.31
$10-\alpha\beta$	34.29	0.71	0.37	0.03	0.31

Ajuste de Wannier – Verificación de parámetros.

Para un “k” fijo

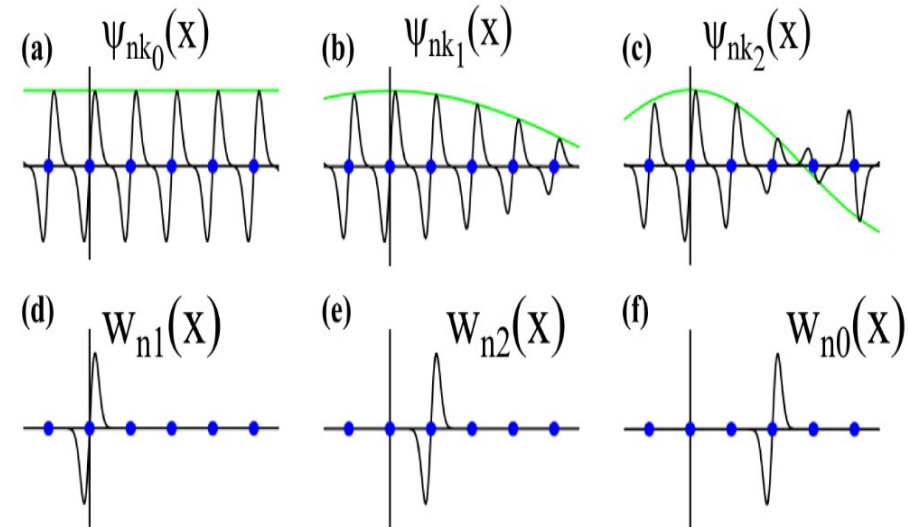


$$\begin{pmatrix} \epsilon_1 & 0 & 0 & 0 & \dots \\ 0 & \epsilon_2 & 0 & 0 & \dots \\ 0 & 0 & \epsilon_3 & 0 & \dots \\ 0 & 0 & 0 & \epsilon_4 & \dots \\ \vdots & \vdots & \vdots & \vdots & \ddots \end{pmatrix}$$



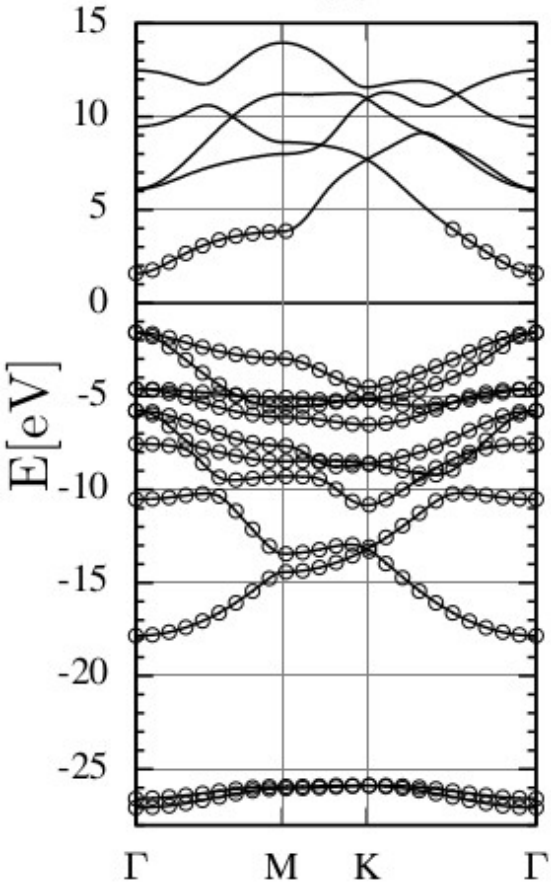
$$|w_{n\mathbf{R}}\rangle = \frac{\Omega}{(2\pi)^3} \int_{ZB} \left[\sum_{m=1} T_{nm}^{(\mathbf{k})} |\psi_{m\mathbf{k}}\rangle \right] e^{i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$

$$\mathbf{M}^{(k,b)} = \mathbf{T}^{(k)\dagger} \mathbf{M}^{0,(k,b)} \mathbf{T}^{(k+b)}$$



Ajuste de Wannier – Verificación de parámetros.

Para un “k” fijo

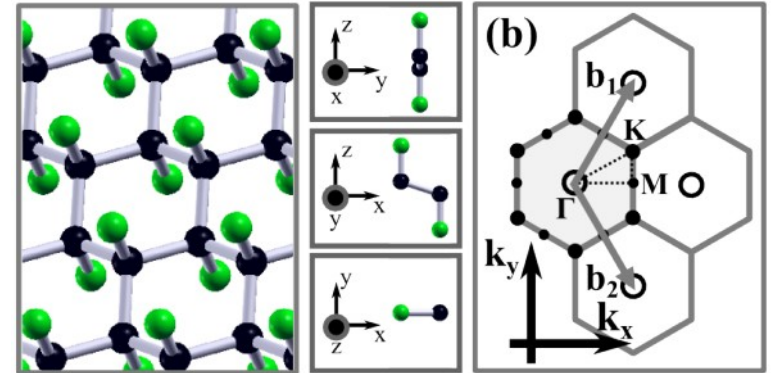


$$\begin{pmatrix} \epsilon_1 & 0 & 0 & 0 & \cdots \\ 0 & \epsilon_2 & 0 & 0 & \cdots \\ 0 & 0 & \epsilon_3 & 0 & \cdots \\ 0 & 0 & 0 & \epsilon_4 & \cdots \\ \vdots & \vdots & \vdots & \vdots & \ddots \end{pmatrix}$$

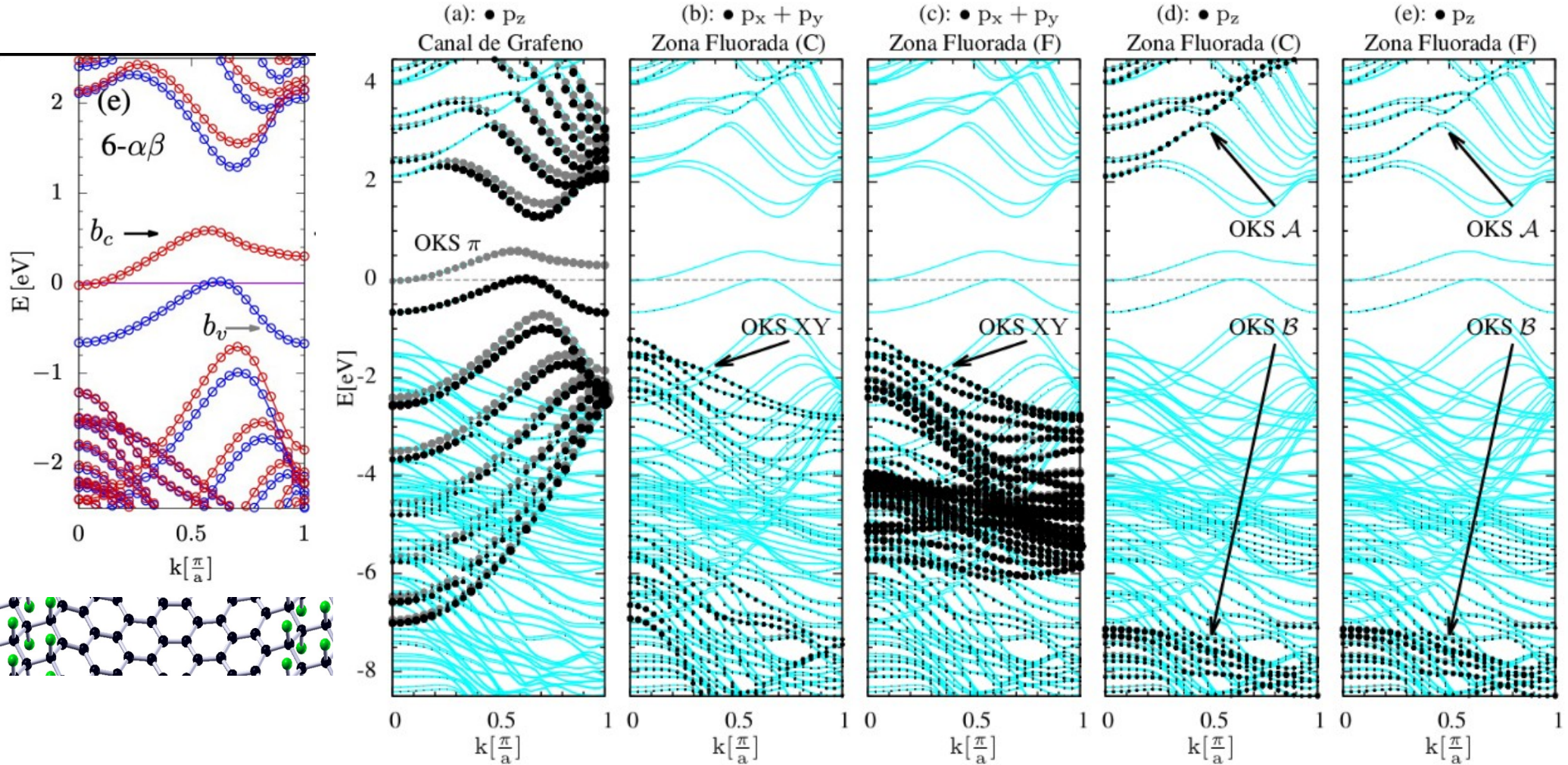
$$\mathbf{H} = \begin{pmatrix} \epsilon_1 & t_{12} & t_{13} & t_{14} & \cdots \\ t_{21} & \epsilon_2 & t_{23} & t_{24} & \cdots \\ t_{31} & t_{32} & \epsilon_3 & t_{34} & \cdots \\ t_{41} & t_{42} & t_{43} & \epsilon_4 & \cdots \\ \vdots & \vdots & \vdots & \vdots & \ddots \end{pmatrix}$$

$$|w_{n\mathbf{R}}\rangle = \frac{\Omega}{(2\pi)^3} \int_{ZB} \left[\sum_{m=1} T_{nm}^{(\mathbf{k})} |\psi_{m\mathbf{k}}\rangle \right] e^{i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$

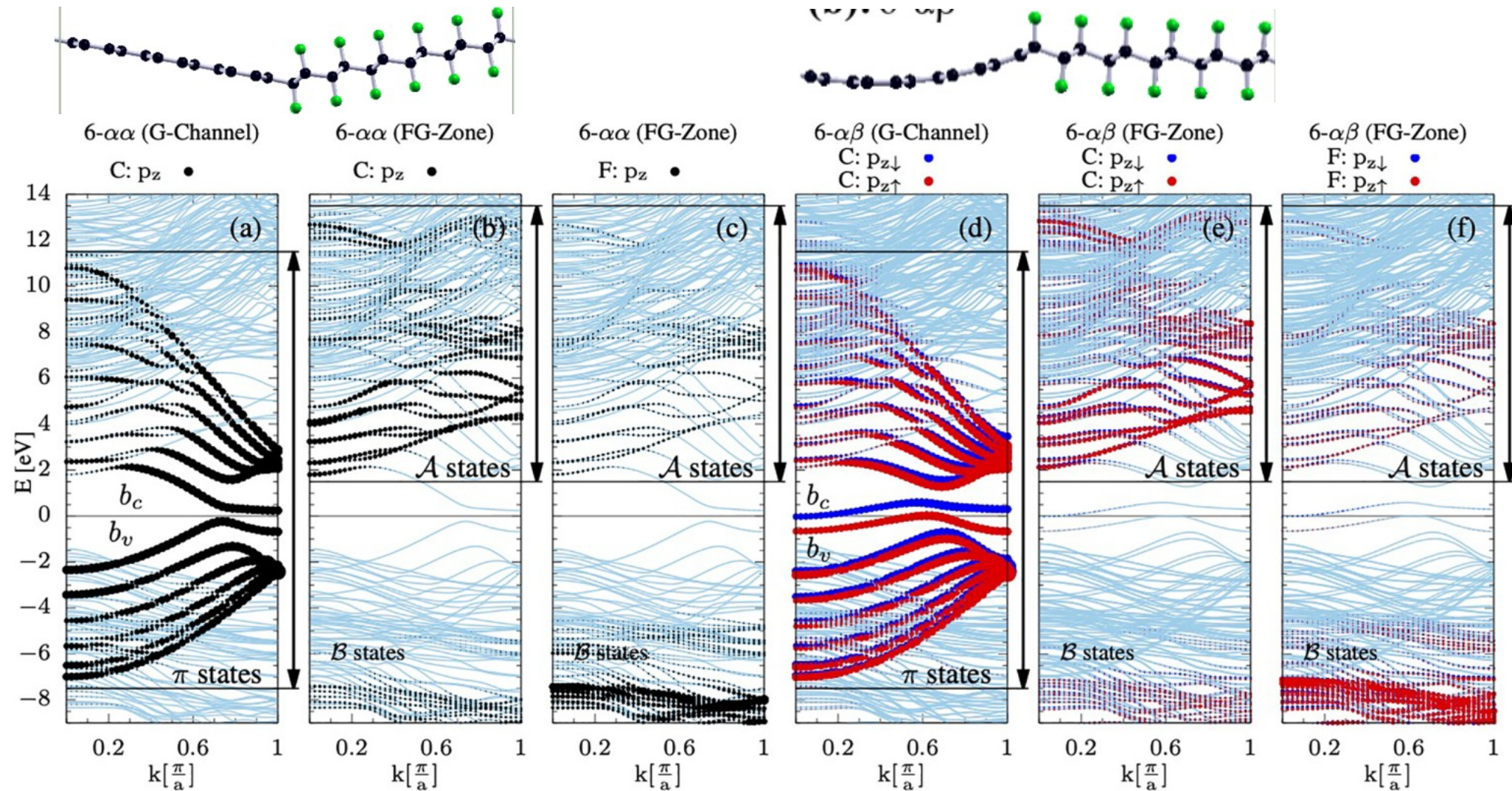
$$\mathbf{M}^{(k,b)} = \mathbf{T}^{(k)\dagger} \mathbf{M}^{0,(k,b)} \mathbf{T}^{(k+b)}$$



Ajuste de Wannier – Verificación de parámetros.



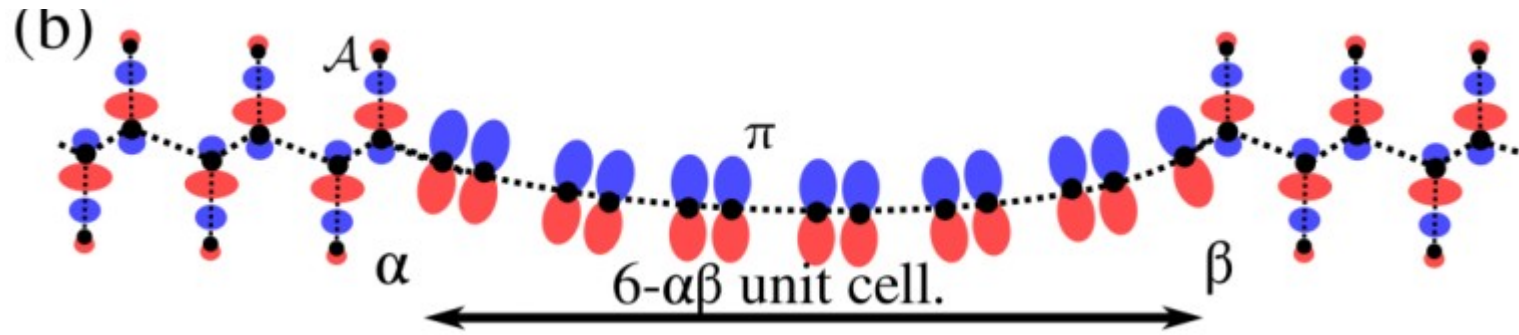
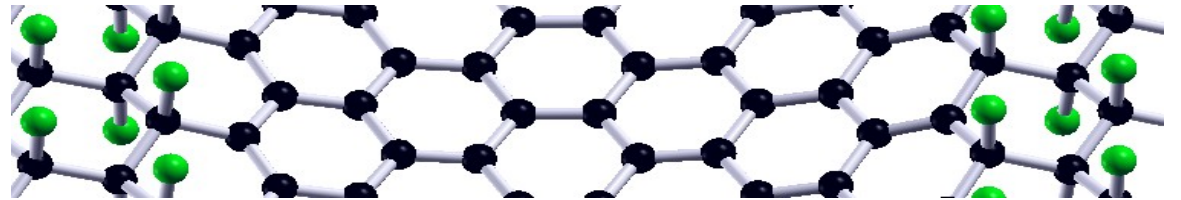
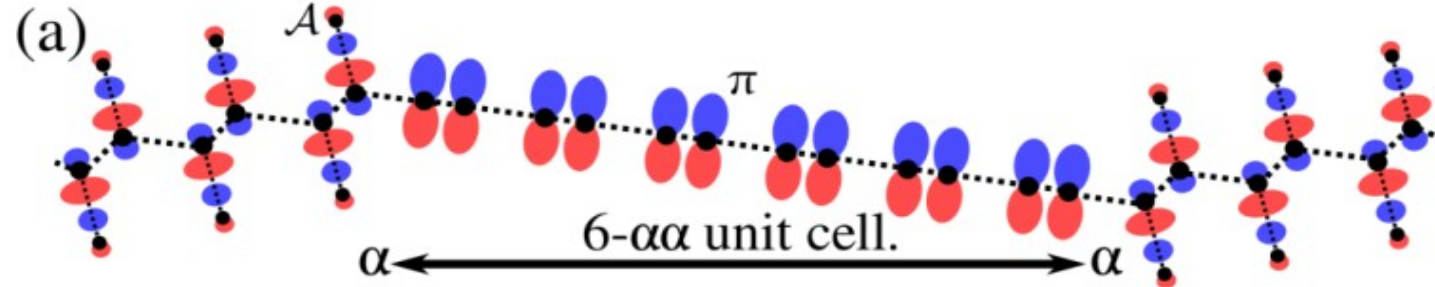
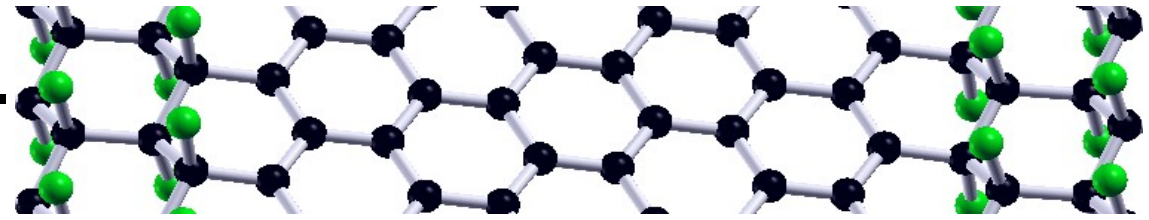
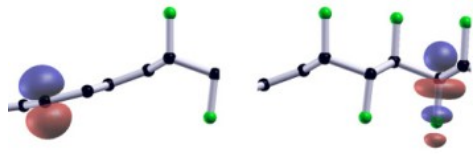
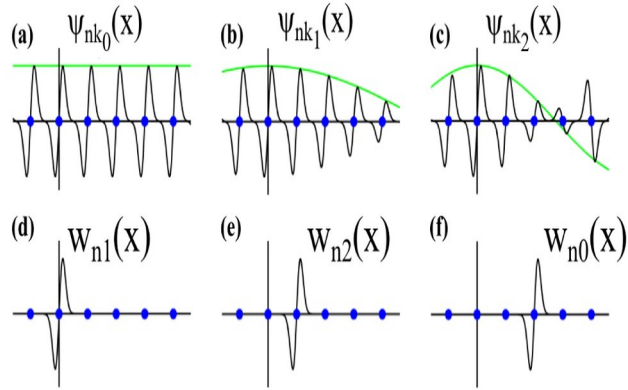
Ajuste de Wannier – Verificación de parámetros.



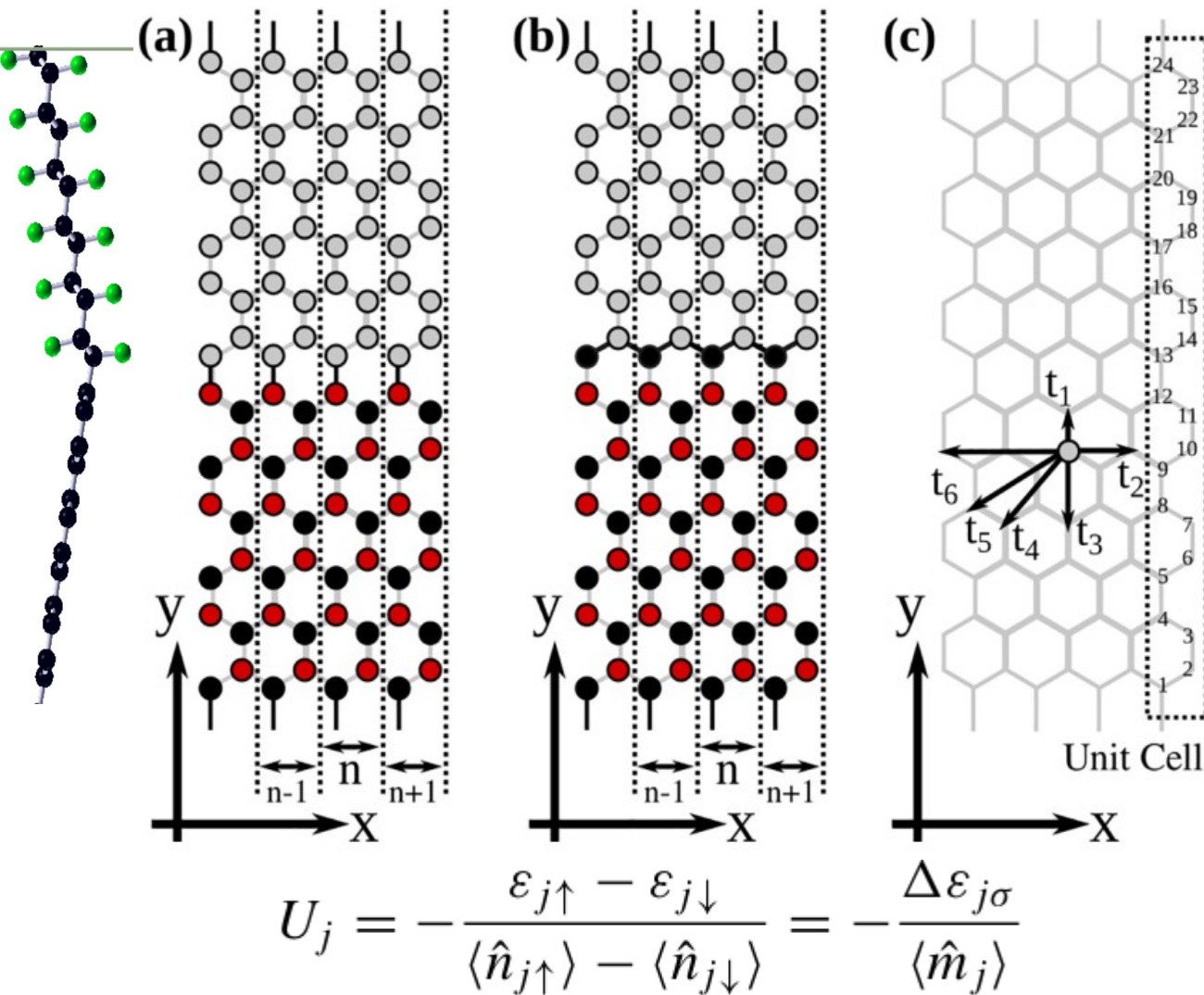
Ajuste de Wannier – Verificación de parámetros.

$$|w_{n\mathbf{R}}\rangle = \frac{\Omega}{(2\pi)^3} \int_{ZB} \left[\sum_{m=1} T_{nm}^{(\mathbf{k})} |\psi_{m\mathbf{k}}\rangle \right] e^{i\mathbf{k}\cdot\mathbf{R}} d\mathbf{k}$$

$$\mathbf{M}^{(k,b)} = \mathbf{T}^{(\mathbf{k})\dagger} \mathbf{M}^{0,(\mathbf{k},b)} \mathbf{T}^{(\mathbf{k}+\mathbf{b})}$$



Modelo de Hubbard y método Hartree-Fock



Funciones de Bloch

$$\mathbf{H} = \begin{pmatrix} \varepsilon_1 & 0 & 0 & 0 & \cdots \\ 0 & \varepsilon_2 & 0 & 0 & \cdots \\ 0 & 0 & \varepsilon_3 & 0 & \cdots \\ 0 & 0 & 0 & \varepsilon_4 & \cdots \\ \vdots & \vdots & \vdots & \vdots & \ddots \end{pmatrix}$$

Funciones de Wannier

$$\mathbf{H} = \begin{pmatrix} \varepsilon_1 & t_{12} & t_{13} & t_{14} & \cdots \\ t_{21} & \varepsilon_2 & t_{23} & t_{24} & \cdots \\ t_{31} & t_{32} & \varepsilon_3 & t_{34} & \cdots \\ t_{41} & t_{42} & t_{43} & \varepsilon_4 & \cdots \\ \vdots & \vdots & \vdots & \vdots & \ddots \end{pmatrix}$$

$$H_{AH} = \sum_{j,\sigma} \varepsilon_j c_{j\sigma}^\dagger c_{j\sigma} - \sum_{j,l,\sigma} t_{jl} c_{j\sigma}^\dagger c_{l\sigma} + \sum_j U_j \hat{n}_{j\uparrow} \hat{n}_{j\downarrow}$$

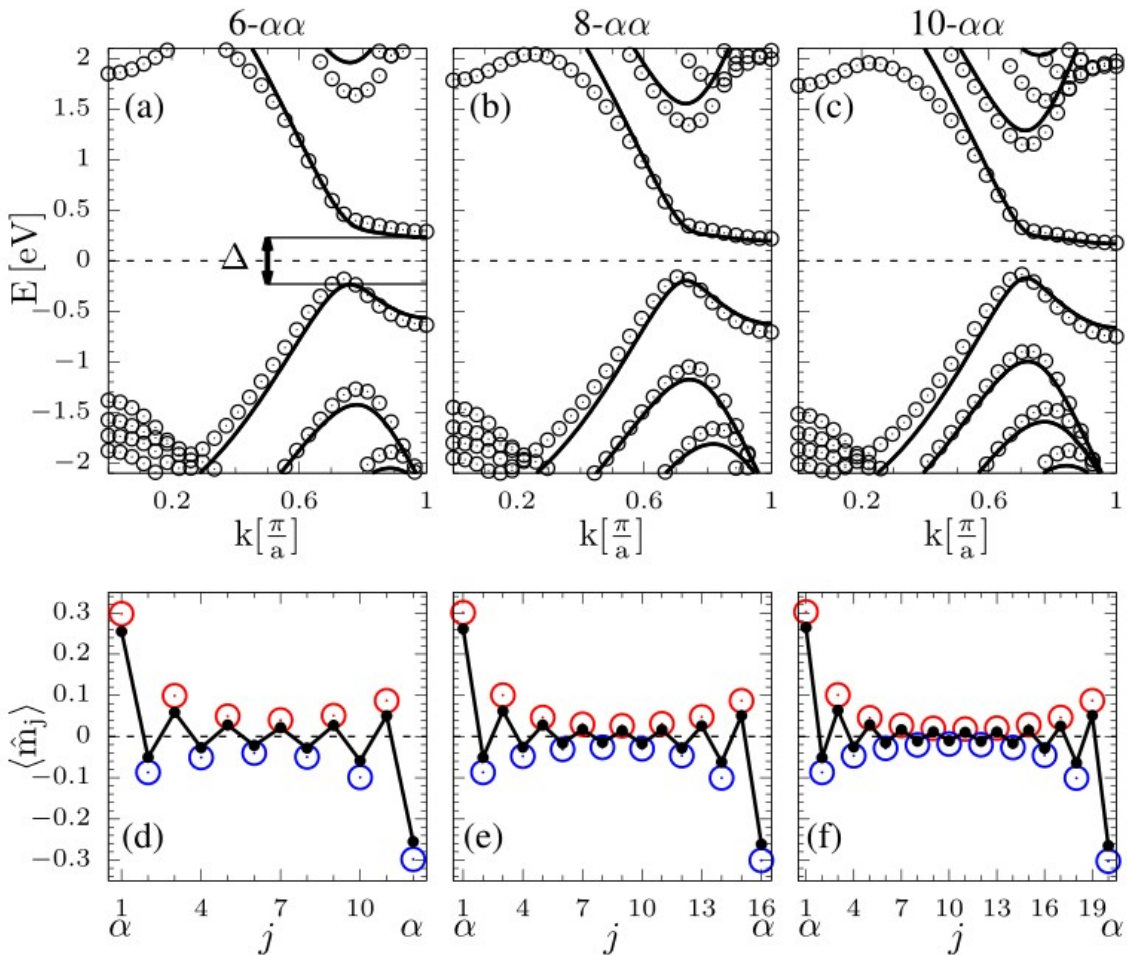
Hartree - Fock

$$\bar{H}_{AH} = \sum_{j,\sigma} \varepsilon_{j\sigma} c_{j\sigma}^\dagger c_{j\sigma} - \sum_{j,l,\sigma} t_{jl} c_{j\sigma}^\dagger c_{l\sigma}$$

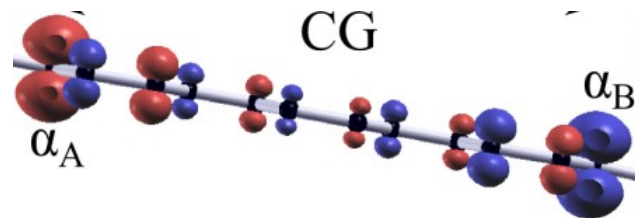
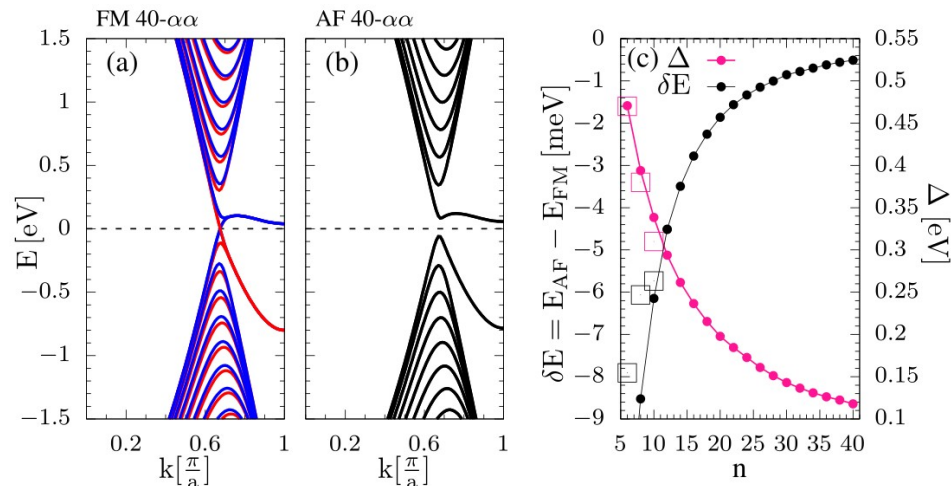
$$\varepsilon_{j\uparrow} = \varepsilon_j + U_j \langle \hat{n}_{j\downarrow} \rangle,$$

$$\varepsilon_{j\downarrow} = \varepsilon_j + U_j \langle \hat{n}_{j\uparrow} \rangle.$$

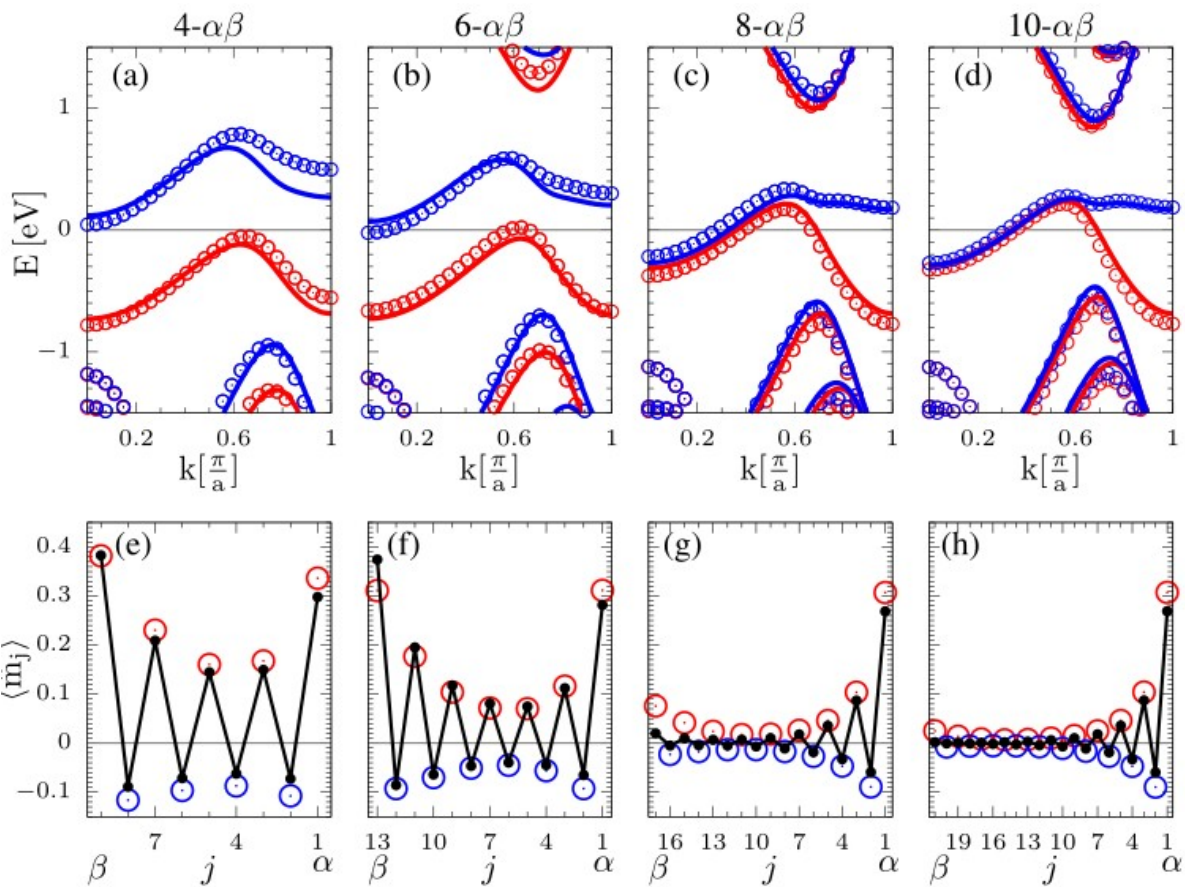
Ajuste de los resultados DFT.



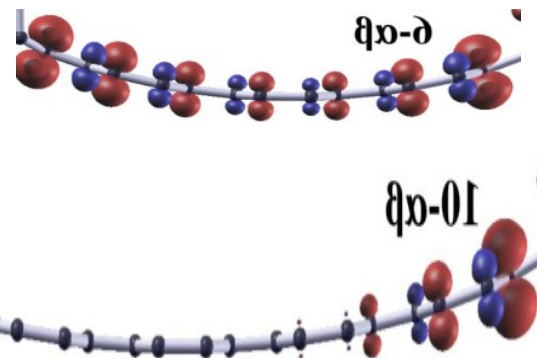
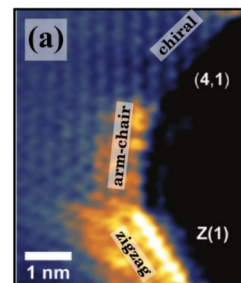
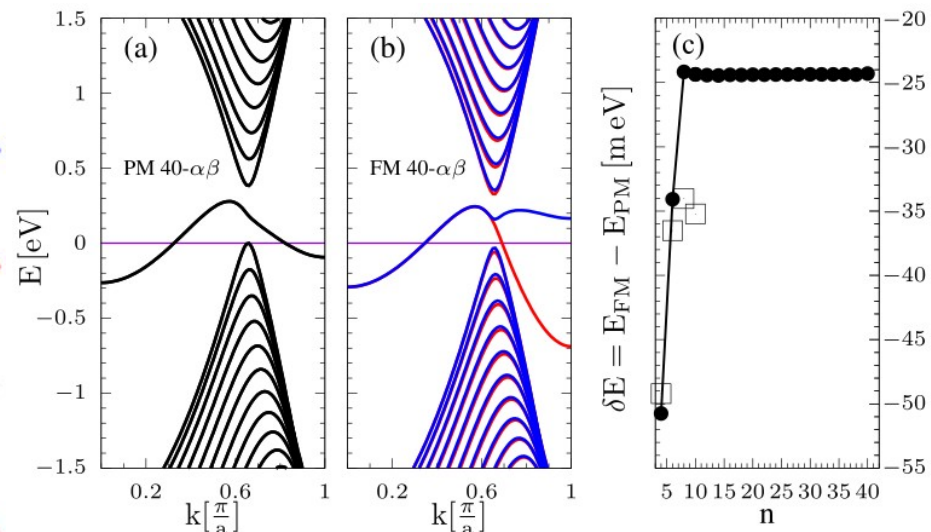
Predicción



Ajuste de los resultados DFT.



Predicción







Conclusiones – Referencias.

1. Los canales de grafeno (F-GNR) tienen propiedades similares a las cintas de grafeno (ZGNR).
2. La diferencia entre estados de borde F-GNR respecto las ZGNR es su localización, que permite sintonizar un cambio de fase respecto el ancho del canal.
- 3 Los orbitales de Wannier reproducen los resultados DFT de sistemas con enlaces covalentes.

PHYSICAL REVIEW B **110**, 115425 (2024)

Electronic and magnetic properties of graphene-fluorographene nanoribbons: Controllable semiconductor-metal transition

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